# General purpose amplification (-12V, -1.5A) US6T8

#### Application

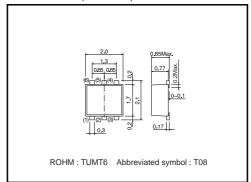
Low frequency amplifier Driver

#### ● Features

- 1) A collector current is large.
- 2) Collector saturation voltage is low.

 $V_{CE (sat)} \le -200 mV$ At  $I_C = -500 \text{mA} / I_B = -25 \text{mA}$ 

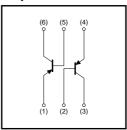
# ●Dimensions (Unit:mm)



# ● Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-base voltage	Vсво	-15	V
Collector-emitter voltage	Vceo	-12	V
Emitter-base voltage	VEBO	-6	V
Callactor aurrent	lc	-1.5	Α
Collector current	ICP	-3	A *1
		400	mW/TOTAL *2
Power dissipation	Pc	1.0	W/TOTAL *3
		0.7	W/ELEMENT *3
Junction temperature	Tj	150	°C
Range of storage temperature	Tsta	-55 to +150	°C

# ●Equivalent circuit



- \*1 Single pulse, Pw=1ms
  \*2 Each Terminal Mounted on a Recommended
  \*3 Mounted on a 25mm×25mm×<sup>1</sup>0.8mm Ceramic substrate

## ●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	-15	_	_	V	Ic=-10μA
Collector-emitter breakdown voltage	BVceo	-12	_	_	V	Ic=-1mA
Emitter-base breakdown voltage	ВУЕВО	-6	_	_	V	I <sub>E</sub> = -10μA
Collector cutoff current	Ісво	_	_	-100	nA	Vсв= −15V
Emitter cutoff current	<b>І</b> ЕВО	_	_	-100	nA	V <sub>EB</sub> = -6V
Collector-emitter saturation voltage	VCE(sat)	_	-85	-200	mV	Ic= -500mA, I <sub>B</sub> = -25mA
DC current gain	hfe	270	_	680	_	Vce= -2V, Ic= -200mA*
Transition frequency	f⊤	_	400	_	MHz	Vc=-2V, I=200mA, f=100MHz *
Corrector output capacitance	Cob	_	12	_	pF	Vсв= −10V, I∈=0A, f=1МНz

<sup>\*</sup>Pulsed

Rev.B

### Packaging specifications

	Package	Taping
Type	Code	TR
	Basic ordering unit (pieces)	3000
US6T8		0

#### Electrical characteristic curves

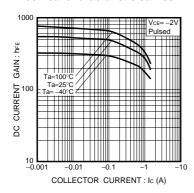


Fig.1 DC current gain vs. collector current

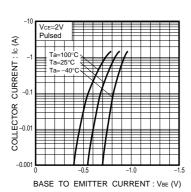


Fig.4 Grounded emitter propagation characteristics

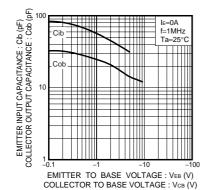


Fig.7 Collector output capacitance vs. collector-base voltage Emitter input capacitance vs. emitter-base voltage

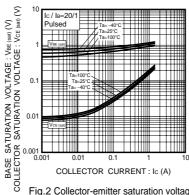


Fig.2 Collector-emitter saturation voltage base-emitter saturation voltage vs. collector current

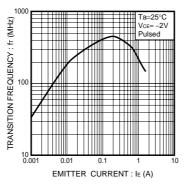


Fig.5 Gain bandwidth product vs. emitter current

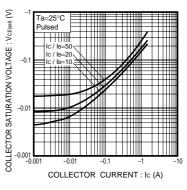


Fig.3 Collector-emitter saturation voltage vs. collector current

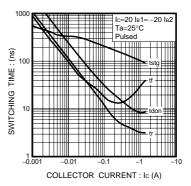


Fig.6 Switching time

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